

## N-Channel Power MOSFET

60V, 27A, 30mΩ

### FEATURES

- Low  $R_{DS(ON)}$  to minimize conductive losses
- Low gate charge for fast power switching
- 100% UIS and  $R_g$  tested.
- 175°C Operating Junction Temperature
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

### KEY PERFORMANCE PARAMETERS

PARAMETER	VALUE	UNIT
$V_{DS}$	60	V
$R_{DS(on)}$ (max)   $V_{GS} = 10V$	30	mΩ
$Q_g$	18	nC

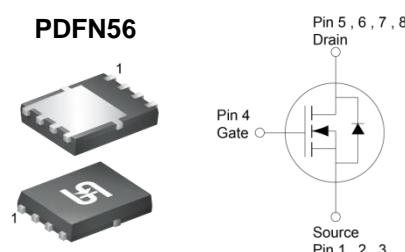
### APPLICATIONS

- BLDC Motor Control
- Battery Power Management
- DC-DC converter
- Secondary Synchronous Rectification



✓  
RoHS  
COMPLIANT

HALOGEN  
FREE



Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	$V_{DS}$	60	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current <sup>(Note 1)</sup>	$I_D$	27	A
$T_C = 25^\circ C$		6	
Pulsed Drain Current	$I_{DM}$	108	A
Single Pulse Avalanche Current <sup>(Note 2)</sup>	$I_{AS}$	12	A
Single Pulse Avalanche Energy <sup>(Note 2)</sup>	$E_{AS}$	21.6	mJ
Total Power Dissipation	$P_D$	56	W
$T_C = 125^\circ C$		19	
Total Power Dissipation	$P_D$	3.1	W
$T_A = 25^\circ C$		1	
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	- 55 to +175	°C

### THERMAL PERFORMANCE

PARAMETER	SYMBOL	LIMIT	UNIT
Junction to Case Thermal Resistance	$R_{\Theta JC}$	2.7	°C/W
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	48	°C/W

**Thermal Performance Note:**  $R_{\Theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins.  $R_{\Theta JA}$  is guaranteed by design while  $R_{\Theta CA}$  is determined by the user's board design. The  $R_{\Theta JA}$  limit presented here is based on mounting on a 1 in<sup>2</sup> pad of 2 oz copper.

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^\circ\text{C}$ unless otherwise noted)						
<b>PARAMETER</b>	<b>CONDITIONS</b>	<b>SYMBOL</b>	<b>MIN</b>	<b>TYP</b>	<b>MAX</b>	<b>UNIT</b>
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{V}$ , $I_D = 250\mu\text{A}$	$BV_{DSS}$	60	--	--	V
Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 250\mu\text{A}$	$V_{GS(\text{TH})}$	2.5	3.4	4.5	V
Gate-Source Leakage Current	$V_{GS} = \pm 20\text{V}$ , $V_{DS} = 0\text{V}$	$I_{GSS}$	--	--	$\pm 100$	nA
Drain-Source Leakage Current	$V_{GS} = 0\text{V}$ , $V_{DS} = 60\text{V}$	$I_{DSS}$	--	--	1	$\mu\text{A}$
	$V_{GS} = 0\text{V}$ , $V_{DS} = 60\text{V}$ $T_J = 125^\circ\text{C}$		--	--	100	
Drain-Source On-State Resistance (Note 3)	$V_{GS} = 10\text{V}$ , $I_D = 6\text{A}$	$R_{DS(\text{on})}$	--	25	30	$\text{m}\Omega$
Forward Transconductance (Note 3)	$V_{DS} = 10\text{V}$ , $I_D = 6\text{A}$	$g_{fs}$	--	32	--	S
<b>Dynamic</b> (Note 4)						
Total Gate Charge	$V_{GS} = 10\text{V}$ , $V_{DS} = 30\text{V}$ , $I_D = 6\text{A}$	$Q_g$	--	18	-	nC
Gate-Source Charge		$Q_{gs}$	--	6	--	
Gate-Drain Charge		$Q_{gd}$	--	4	--	
Input Capacitance	$V_{GS} = 0\text{V}$ , $V_{DS} = 30\text{V}$ $f = 1.0\text{MHz}$	$C_{iss}$	--	1110	--	pF
Output Capacitance		$C_{oss}$	--	71	--	
Reverse Transfer Capacitance		$C_{rss}$	--	19	--	
Gate Resistance	$f = 1.0\text{MHz}$	$R_g$	0.7	2.4	4.8	$\Omega$
<b>Switching</b> (Note 4)						
Turn-On Delay Time	$V_{GS} = 10\text{V}$ , $V_{DS} = 30\text{V}$ , $I_D = 6\text{A}$ , $R_G = 2\Omega$	$t_{d(\text{on})}$	--	3	--	ns
Turn-On Rise Time		$t_r$	--	19	--	
Turn-Off Delay Time		$t_{d(\text{off})}$	--	7	--	
Turn-Off Fall Time		$t_f$	--	17	--	
<b>Source-Drain Diode</b>						
Forward Voltage (Note 3)	$V_{GS} = 0\text{V}$ , $I_S = 6\text{A}$	$V_{SD}$	--	--	1.2	V
Reverse Recovery Time	$I_S = 6\text{A}$ , $dI/dt = 100\text{A}/\mu\text{s}$	$t_{rr}$	--	15	--	ns
Reverse Recovery Charge		$Q_{rr}$	--	10	--	nC

**Notes:**

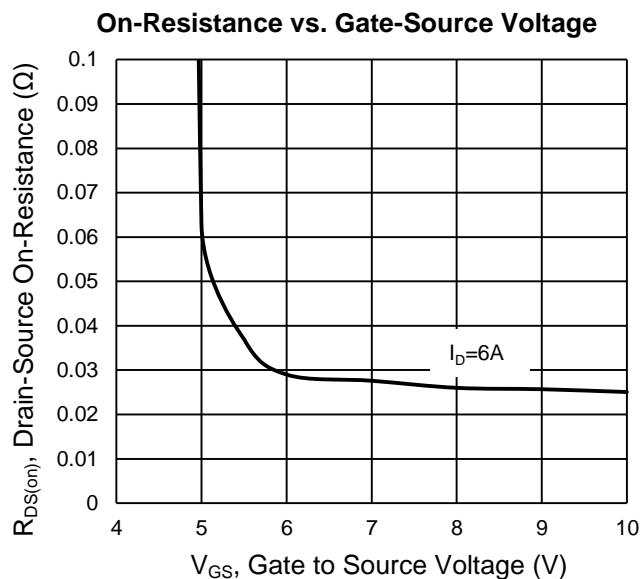
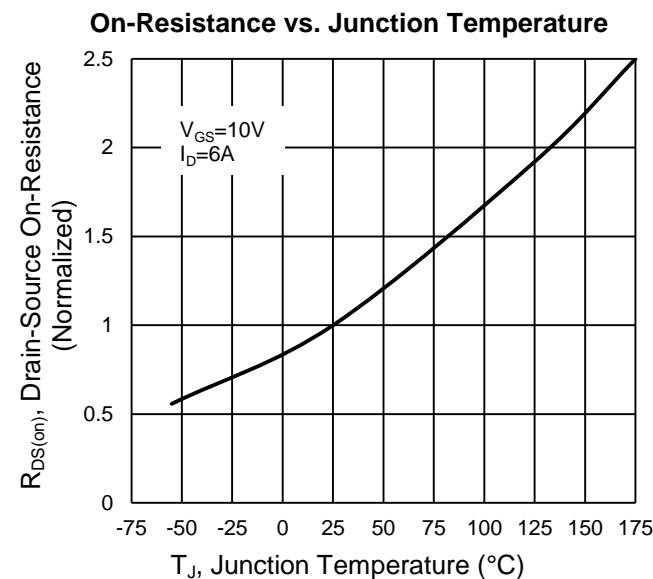
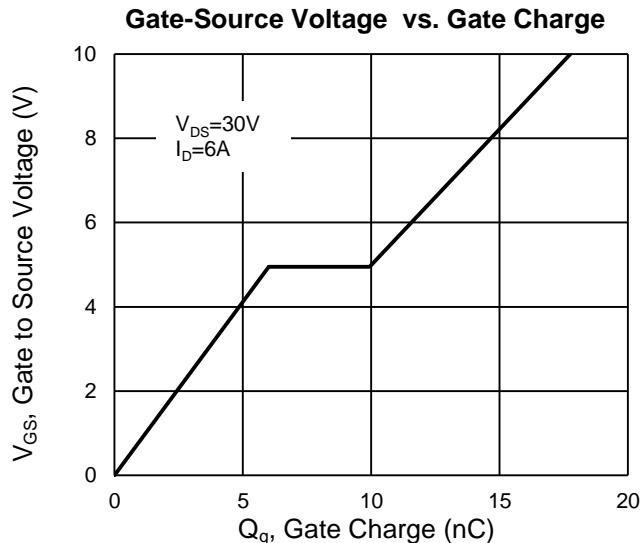
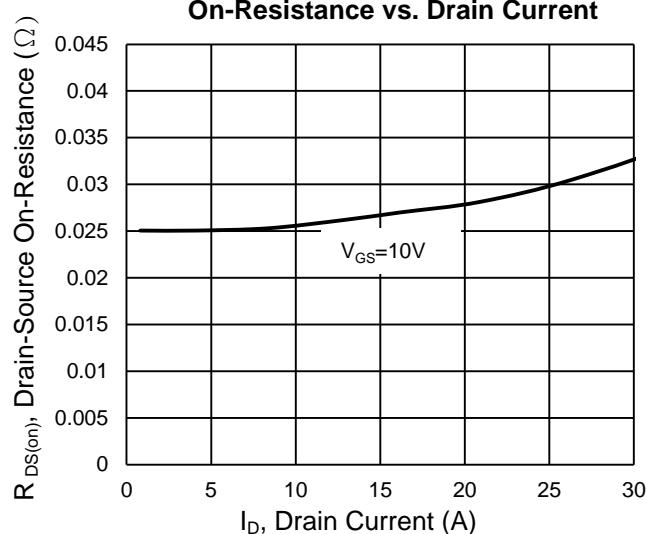
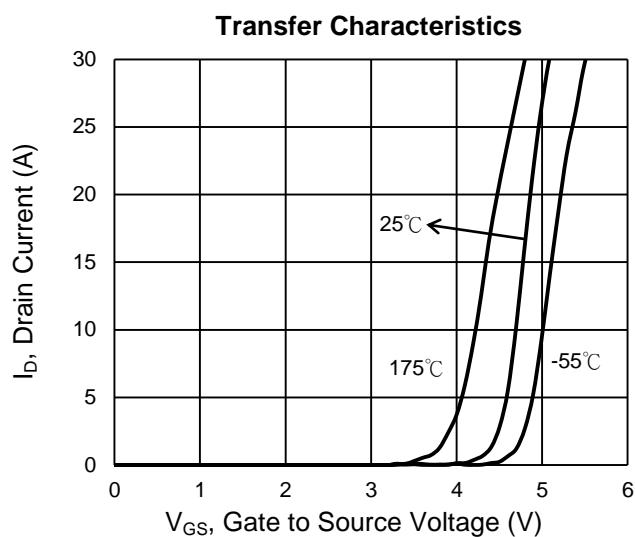
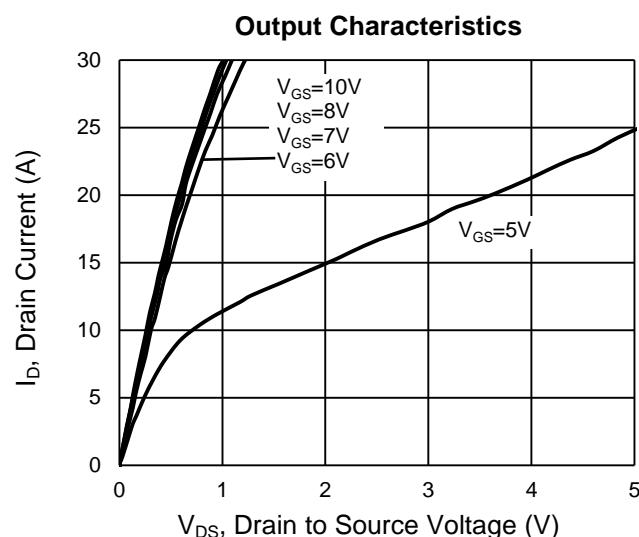
1. Silicon limited current only.
2.  $L = 0.3\text{mH}$ ,  $V_{GS} = 10\text{V}$ ,  $V_{DD} = 30\text{V}$ ,  $R_G = 25\Omega$ ,  $I_{AS} = 12\text{A}$ , Starting  $T_J = 25^\circ\text{C}$
3. Pulse test: Pulse Width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .
4. Switching time is essentially independent of operating temperature.

**ORDERING INFORMATION**

<b>PART NO.</b>	<b>PACKAGE</b>	<b>PACKING</b>
TSM300NB06CR RLG	PDFN56	2,500pcs / 13" Reel

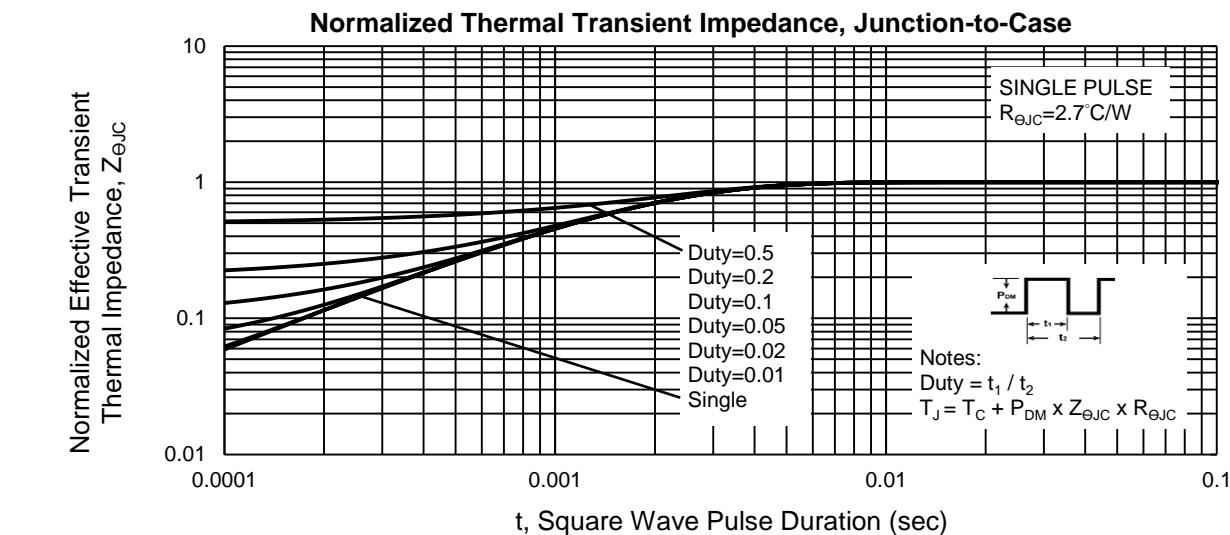
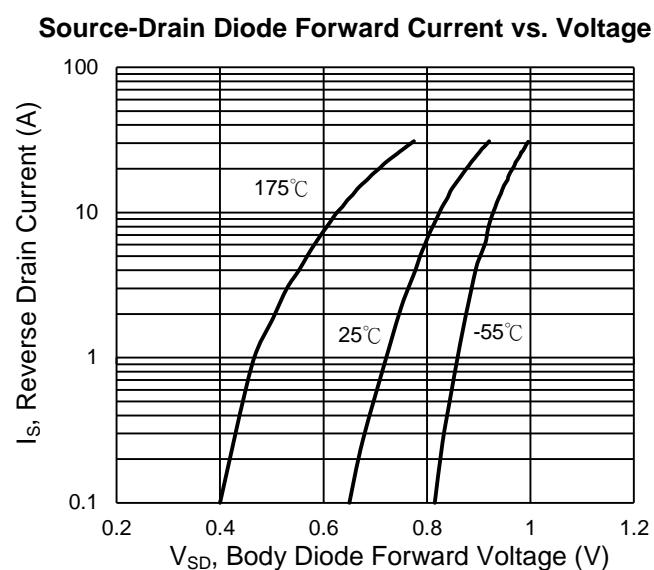
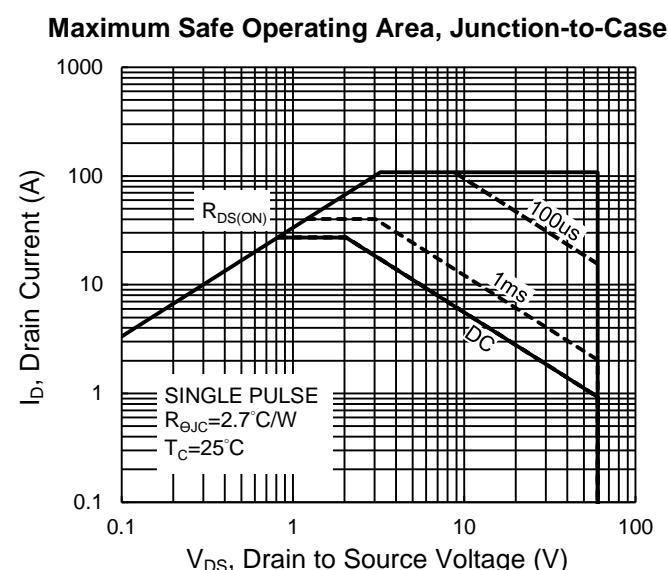
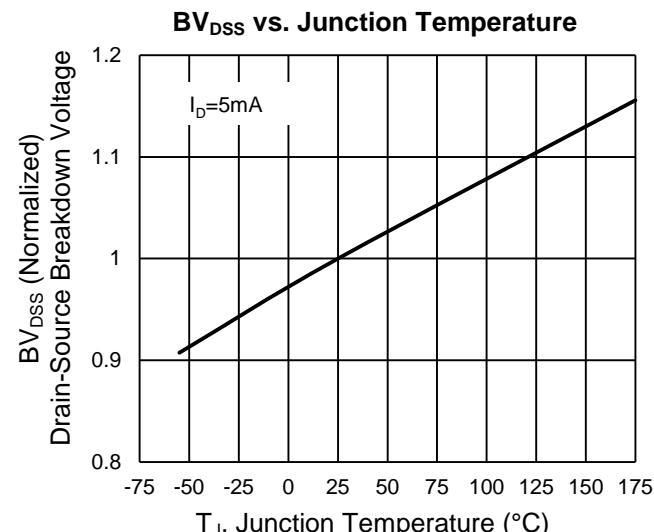
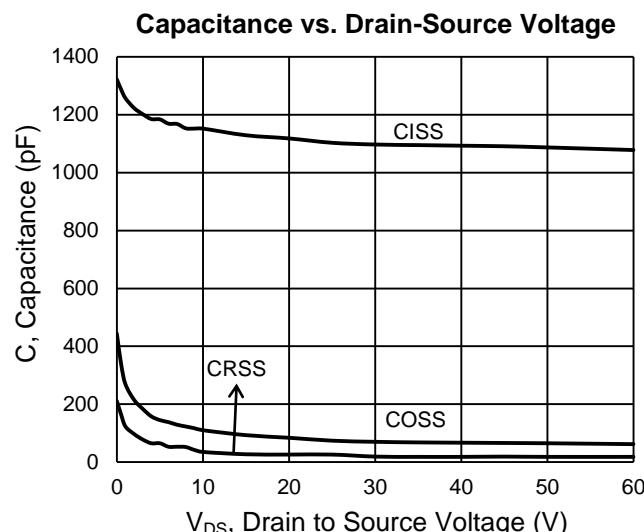
## CHARACTERISTICS CURVES

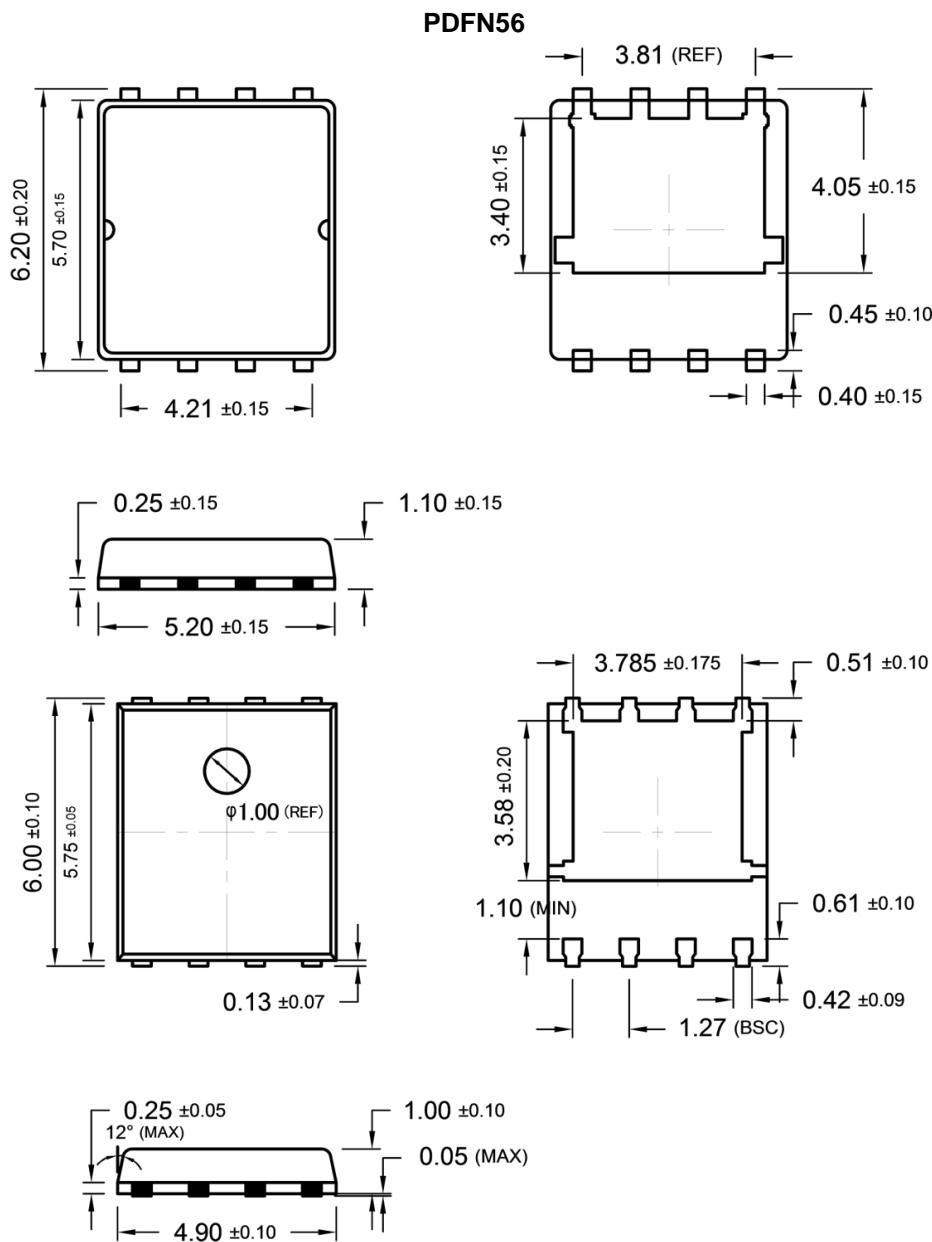
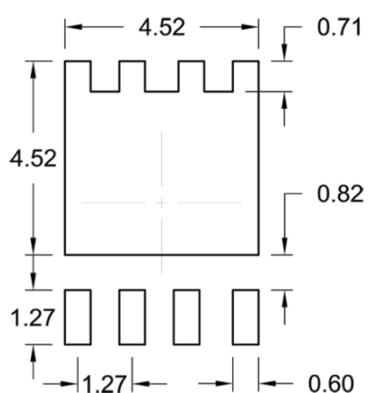
( $T_A = 25^\circ\text{C}$  unless otherwise noted)



## CHARACTERISTICS CURVES

( $T_A = 25^\circ\text{C}$  unless otherwise noted)



**PACKAGE OUTLINE DIMENSIONS** (Unit: Millimeters)

**SUGGESTED PAD LAYOUT** (Unit: Millimeters)

**MARKING DIAGRAM**


**G** = Halogen Free  
**Y** = Year Code  
**WW** = Week Code (01~52)  
**F** = Factory Code

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